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DESCRIPTION

The A7231 is a current mode monolithic buck voltage converter. Operating with an input range of 4.5V-18V, the A7231 delivers 3A of continuous output current with two integrated N-Channel MOSFETs. At light loads, regulators operate in low frequency to maintain high efficiency and low output ripple.

The A7231 guarantees robustness with over current protection, thermal protection, start-up current run-away protection, and input under voltage lockout.

The A7231 is available in TSOT-26 package.

ORDERING INFORMATION

Package Type	Part Number			
TSOT-26	TE6	A7231TE6R		
		A7231TE6VR		
Noto	V: Halogen free Package			
Note	R: Tape & Reel			
AiT provides all RoHS products				
Suffix " V " means Halogen free Package				

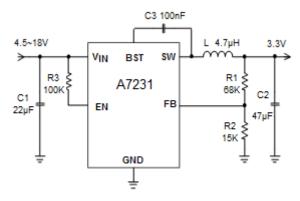
FEATURES

- 4.5V to 18V operating input range 3A output current
- Up to 95% efficiency •
- High efficiency at light load •
- Fixed 420kHz Switching frequency •
- Input under voltage lockout •
- Start-up current run-away protection
- Over current protection and Hiccup
- Thermal protection
- Available in TSOT-26 Package •

APPLICATION

- **Distributed Power Systems**
- **Networking Systems**
- FPGA, DSP, ASIC Power Supplies
- Green Electronics/ Appliances
- **Notebook Computers** .

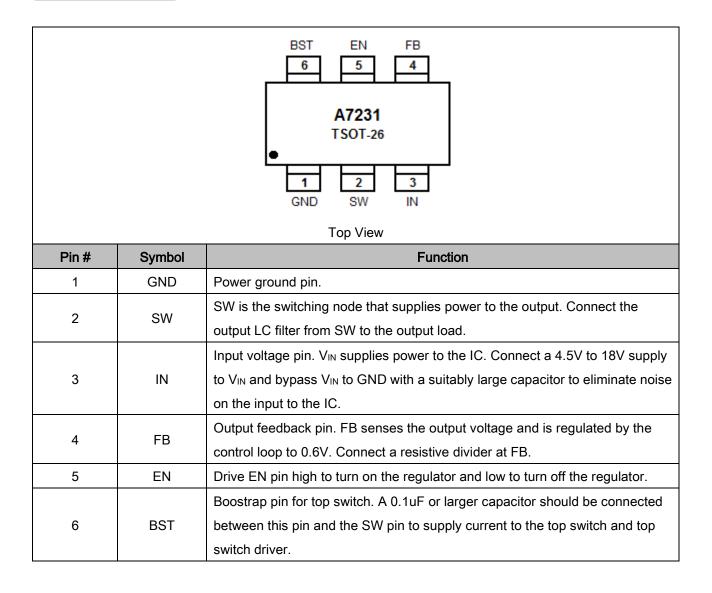
TYPICAL APPLICATION



3A Buck Voltage Converter



PIN DESCRIPTION





ABSOLUTE MAXIMUM RATINGS

V _{IN} , EN, SW PIN	-0.3V ~ 19V
BST PIN	SW-0.3V to SW+5V
FB PIN	-0.3V to 2.5V
Junction Temperature ^{NOTE1,2}	150°C
Lead Temperature	260°C
Storage Temperature	-65°C ~ +150°C

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: The A7231 guarantees robust performance from -40°C to 150°C junction temperature. The junction temperature range specification is assured by design, characterization and correlation with statistical process controls.

NOTE2: The A7231 includes thermal protection that is intended to protect the device in overload conditions. Thermal protection is active when junction temperature exceeds the maximum operating junction temperature. Continuous operation over the specified absolute maximum operating junction temperature may damage the device.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Max	Units
Input Voltage	VIN	4.5	18	V
Output Voltage	V _{OUT}	0.8	16.2	V
Junction Temperature	TJ	-40	125	°C

THERMAL PERFORMANCENOTE3

Package	θյΑ	θις
TSOT-26	110°C/W	55°C/W

NOTE3: Measured on JESD51-7, 4-layer PCB.



ELECTRICAL CHARACTERISTICS

 V_{IN} =12V, T_A=25°C, unless otherwise stated.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
V _{IN} Undervoltage Lockout Threshold	V _{IN_MIN}	V _{IN} falling		3.9	4.1	V
V _{IN} Undervoltage Lockout Hysteresis	VIN_MIN_HYST	V _{IN} rising		250		mV
Shutdown Supply Current	Isd	V _{EN} =0V		0.2	0.3	μA
Supply Current	Ιq	V_{EN} =5V, V_{FB} =2V		80	100	μA
Feedback Voltage	V _{FB}		588	600	612	mV
Top Switch Resistance ^{NOTE4}	Rds(on)t			115		mΩ
Bottom Switch ResistanceNOTE4	R _{DS(ON)B}			71		mΩ
Top Switch Leakage Current	ILEAK_TOP	V _{IN} =16V, V _{EN} =0V, V _{SW} =0V			0.5	μA
Bottom Switch Leakage Current	I _{LEAK_BOT}	V _{IN} =16V, V _{EN} =0V, V _{SW} =0V			0.5	μA
Top Switch Current Limit ^{NOTE4}	ILIM_TOP	Minimum Duty Cycle		5.5		А
Switch Frequency	Fsw			420		kHz
Minimum On Time ^{NOTE4}	T _{ON_MIN}			100		ns
Minimum Off Time ^{NOTE4}	TOFF_MIN	V _{FB} =0.7V		130		ns
EN Shut Down Threshold Voltage	V _{EN_TH}	V _{EN} falling, FB=0V		1.2		V
EN Shut Down Hysteresis	V _{EN_HYST}	V _{EN} rising, FB=0V		100		mV
Thermal Shutdown ^{NOTE4}	T _{TSD}			145		°C
Temperature Hysteresis ^{NOTE4}	THYS			20		°C

NOTE4: Guaranteed by design.

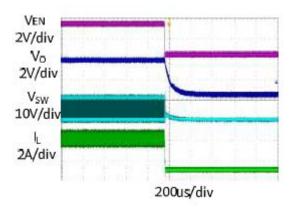


TYPICAL PERFORMANCE CHARACTERISTICS

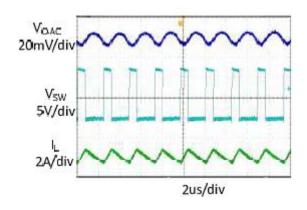
 V_{IN} =12V, V_{OUT} = 3.3V, L = 4.7µH, C_{OUT} = 47µF, T_A = +25°C, unless otherwise noted

1. Steady State Test VIN=12V, VOUT=3.3V, IOUT=3A VoAc 20mV/div V_{SW} 5V/div L 2A/div 2us/div

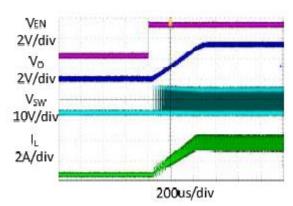
3. Shutdown through Enable VIN=12V, VOUT=3.3V, IOUT=3A(Resistive load)



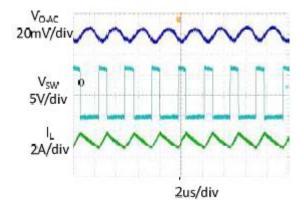
5. Medium Load Operation 1A LOAD



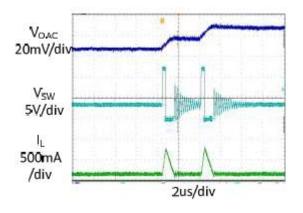
- 2. Startup through Enable
 - VIN=12V, VOUT=3.3V, IOUT=3A(Resistive load)



4. Heavy Load Operation 2A LOAD

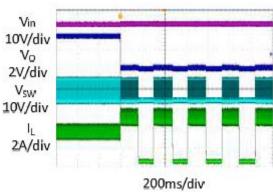


6. Light Load Operation 0 A LOAD



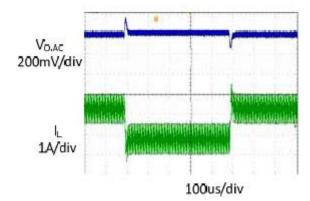


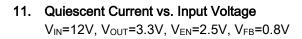
7. **Short Circuit Protection** VIN=12V, VOUT=3.3V, IOUT=3A- Short

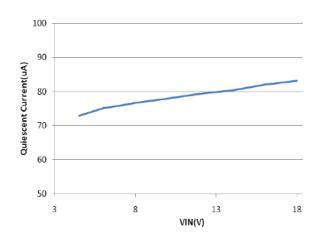


Load Transient 9.

 $1.5A \text{ LOAD} \rightarrow 3A \text{ LOAD} \rightarrow 1.5A \text{ LOAD}$

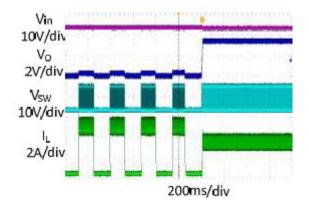






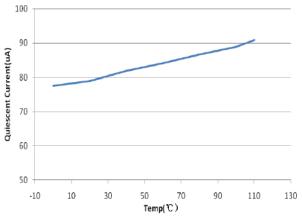
8. Short Circuit Recovery

VIN=12V, VOUT=3.3V, IOUT= Short-3A

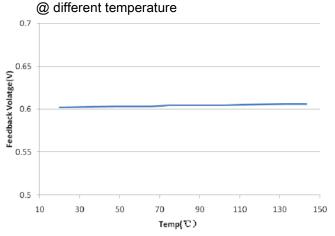


10. Quiescent Current vs. Temp

VIN=12V, VOUT=3.3V, VEN=2.5V, VFB=0.8V

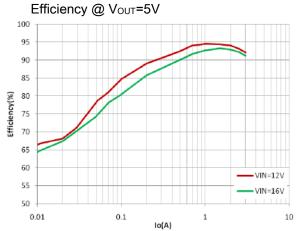


12. Feedback Voltage vs. Temp. V_{IN} =5V, V_{EN} =2.5V, Sweep FB voltage



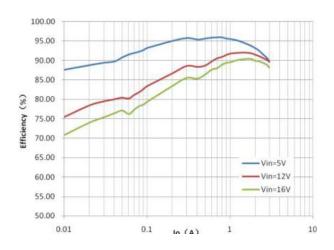


13. Quiescent Current @ Temperature =25°C



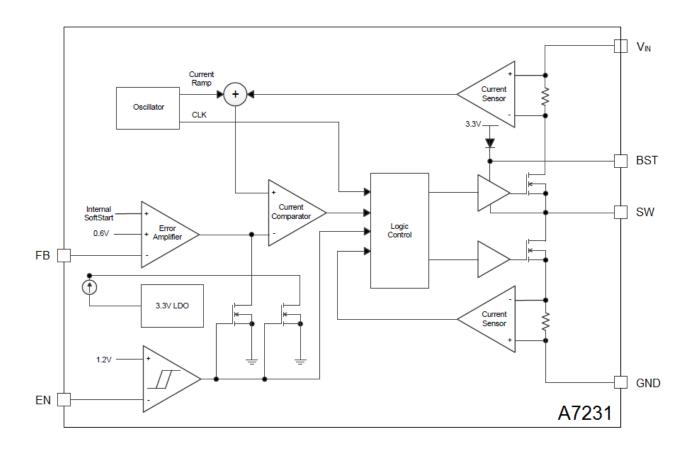


14. Efficiency @ Vout=3.3V





BLOCK DIAGRAM





DETAILED INFORMATION

The A7231 is a synchronous, buck voltage converter.

Current-Mode Control

The A7231 utilizes current-mode control to regulate the FB voltage. Voltage at the FB pin is regulated at 0.6V so that by connecting an appropriate resistor divider between V_{OUT} and GND, designed output voltage can be achieved.

PFM Mode

The A7231 operates in PFM mode at light load. In PFM mode, switch frequency decreases when load current drops to boost power efficiency at light load by reducing switch-loss, while switch frequency increases when load current rises, minimizing output voltage ripples.

Internal Soft-start

Soft-Start makes output voltage rising smoothly follow an internal SS voltage until SS voltage is higher than the internal reference voltage. It can provide overshoot of output voltage when startup.

Power Switch

N-Channel MOSFET switches are integrated on the A7231 to down convert the input voltage to the regulated output voltage. Since the top MOSFET needs a gate voltage greater than the input voltage, a boost capacitor connected between BST and SW pins is required to drive the gate of the top switch. The boost capacitor is charged by the internal 3.3V rail when SW is low.

VIN Under-Voltage Protection

A resistive divider can be connected between V_{IN} and ground, with the central tap connected to EN, so that when V_{IN} drops to the pre-set value, EN drops below 1.2V to trigger input under voltage lockout protection.

Output Current Run-Away Protection

At start-up, due to the high voltage at input and low voltage at output, current inertia of the output inductance can be easily built up, resulting in a large start-up output current. A valley current limit is designed in the A7231 so that only when output current drops below the valley current limit can the top power switch be turned on. By such control mechanism, the output current at start-up is well controlled.



Over Current Protection and Hiccup

A7231 has a cycle-by-cycle current limit. When the inductor current triggers current limit, A7231 enters hiccup mode and periodically restart the chip. A7231 will exit hiccup mode while not triggering current limit.

Thermal Protection

When the temperature of the A7231 rises above 145°C, it is forced into thermal shut-down. Only when core temperature drops below 125°C can the regulator becomes active again.

Application Information

Output Voltage Set

The output voltage is determined by the resistor divider connected at the FB pin, and the voltage ratio is:

$$V_{FB} = V_{OUT} x \frac{R_2}{R_2 + R_1}$$

where V_{FB} is the feedback voltage and V_{OUT} is the output voltage.

Choose R2 around $10k\Omega \sim 15k\Omega$, and then R₁ can be calculated by:

$$\mathbf{R}_1 = \left(\frac{\mathbf{V}_{\text{OUT}}}{\mathbf{0.6}} - \mathbf{1}\right) \mathbf{x} \, \mathbf{R}_2$$

The following table lists the recommended values.

Vout(V)	R₁(kΩ)	R₂(kΩ)
2.5	47	15
3.3	49.5	11
5	110	15

Input Capacitor

The input capacitor is used to supply the AC input current to the step-down converter and maintaining the DC input voltage. The ripple current through the input capacitor can be calculated by:

$$I_{C1} = I_{LOAD} x \sqrt{\frac{V_{OUT}}{V_{IN}} x \left(1 - \frac{V_{OUT}}{V_{IN}}\right)}$$

where I_{LOAD} is the load current, V_{OUT} is the output voltage, V_{IN} is the input voltage.

Thus the input capacitor can be calculated by the following equation when the input ripple voltage is determined.

$$C_{1} = \frac{I \text{LOAD}}{\text{fs } x \Delta \text{IN}} x \frac{\text{VOUT}}{\text{VIN}} x \left(1 - \frac{\text{VOUT}}{\text{VIN}}\right)$$

typically allowed to be 30% of the maximum



where C1 is the input capacitance value, f_S is the switching frequency, ΔV_{IN} is the input ripple voltage.

The input capacitor can be electrolytic, tantalum or ceramic. To minimizing the potential noise, a small X5R or X7R ceramic capacitor, i.e. 0.1uF, should be placed as close to the IC as possible when using electrolytic capacitors.

A 22uF ceramic capacitor is recommended in typical application.

Output Capacitor

The output capacitor is required to maintain the DC output voltage, and the capacitance value determines the output ripple voltage. The output voltage ripple can be calculated by:

$$\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{f_{\text{S}} \times L} \times \left(1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}\right) \times \left(R_{\text{ESR}} + \frac{1}{8 \times f_{\text{S}} \times C_2}\right)$$

where C_2 is the output capacitance value and R_{ESR} is the equivalent series resistance value of the output capacitor.

The output capacitor can be low ESR electrolytic, tantalum or ceramic, which lower ESR capacitors get lower output ripple voltage.

The output capacitors also affect the system stability and transient response, and a 47uF ceramic capacitor is recommended in typical application.

Inductor

The inductor is used to supply constant current to the output load, and the value determines the ripple current which affect the efficiency and the output voltage ripple. The ripple current is switch current limit, thus the inductance value can be calculated by:

$$L = \frac{V_{OUT}}{f_{S} x \Delta I_{L}} x \left(1 - \frac{V_{OUT}}{V_{IN}} \right)$$

where V_{IN} is the input voltage, V_{OUT} is the output voltage, fs is the switching frequency, and ΔI_L is the peak-to-peak inductor ripple current.

External Boostrap Capacitor

A boostrap capacitor is required to supply voltage to the top switch driver. A 0.1uF low ESR ceramic capacitor is recommended to connected to the BST pin and SW pin.

Load Transient Improvement

To improve the load transient performance, a feed forward capacitor (Cff) can be added in parallel with the feedback resistor (R₁). (Figure 1.). At the same time, to avoid the voltage offset which is caused by substrate





PCB Layout Note

For minimum noise problem and best operating performance, the PCB is preferred to following the guidelines as reference.

- Place the input decoupling capacitor as close to A7231 (V_{IN} pin and PGND) as possible to eliminate noise at the input pin. The loop area formed by input capacitor and GND must be minimized.
- 2. Put the feedback trace as far away from the inductor and noisy power traces as possible.
- 3. The ground plane on the PCB should be as large as possible for better heat dissipation.

injection, a 20k resistor (R0) is recommended to insert between the FB PIN and resistance divider.



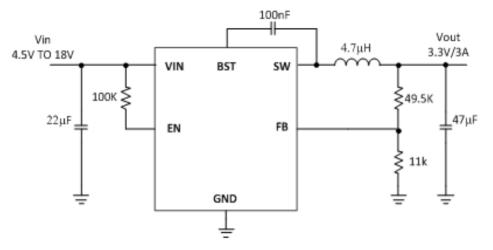
REFERENCE DESIGN

Reference 1:

V_{IN} : 4.5V ~ 18 V

Vout: 3.3V

Iout: 0~3A

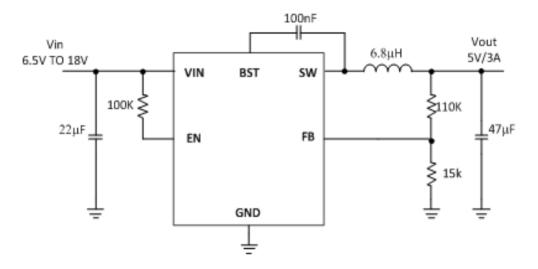


Reference 2:

V_{IN} : 6.5V ~ 18 V

VOUT: 5V

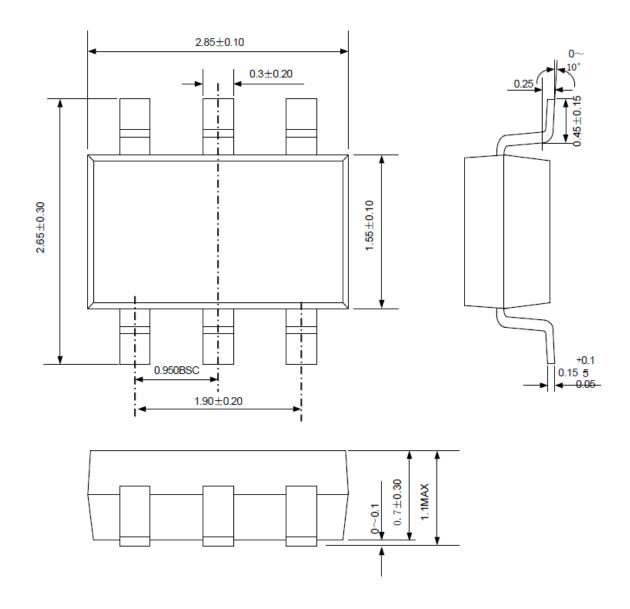
Іо∪т: 0~3А





PACKAGE INFORMATION

Dimension in TSOT-26 (Unit: mm)





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